# 450 mA, Ultra-Low Noise and High PSRR LDO Regulator for RF and Analog Circuits

The NCP148 is a linear regulator capable of supplying 450 mA output current. Designed to meet the requirements of RF and analog circuits, the NCP148 device provides low noise, high PSRR, low quiescent current, and very good load/line transients. The NCP148 offers soft–start function with optimized slew rate control to use in camera module. The device is designed to work with a 1  $\mu$ F input and a 1  $\mu$ F output ceramic capacitor. It is available in ultra–small 0.35P, 0.65 mm x 0.65 mm Chip Scale Package (CSP).

### Features

- Operating Input Voltage Range: 1.9 V to 5.5 V
- Available in Fixed Voltage Option: 1.8 V to 5.14 V
- Optimized Start-up Slew Rate for Camera Sensor
- ±2% Accuracy Over Load/Temperature
- Low Quiescent Current Typ. 55 µA
- Standby Current: Typ. 0.1 µA
- Very Low Dropout: 150 mV at 450 mA
- Ultra High PSRR: Typ. 98 dB at 20 mA, f = 1 kHz
- Ultra Low Noise: 10 µV<sub>RMS</sub>
- Stable with a 1 µF Small Case Size Ceramic Capacitors
- Available in WLCSP4 0.65 mm x 0.65 mm x 0.33 mm CASE 567JZ
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **Typical Applications**

- Camera Modules
- Battery-powered Equipment
- Smartphones, Tablets
- Cameras, DVRs, STB and Camcorders



Figure 1. Typical Application Schematics



# **ON Semiconductor®**

www.onsemi.com



X or XX = Specific Device Code M = Date Code

### PIN CONNECTIONS



### ORDERING INFORMATION

See detailed ordering and shipping information on page 11 of this data sheet.





### **PIN FUNCTION DESCRIPTION**

Pin No.	Pin Name	Description		
A1	IN	Input voltage supply pin		
A2	OUT	Regulated output voltage. The output should be bypassed with small 1 $\mu\text{F}$ ceramic capacitor.		
B1	EN	Chip enable: Applying $V_{EN}$ < 0.4 V disables the regulator, Pulling $V_{EN}$ > 1.2 V enables the LDO.		
B2	GND	Common ground connection		
-	EPAD	Expose pad should be tied to ground plane for better power dissipation		

### **ABSOLUTE MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V <sub>IN</sub>	–0.3 V to 6	V
Output Voltage	V <sub>OUT</sub>	–0.3 to V <sub>IN</sub> + 0.3, max. 6 V	V
Chip Enable Input	V <sub>CE</sub>	–0.3 to V <sub>IN</sub> + 0.3, max. 6 V	V
Output Short Circuit Duration	t <sub>SC</sub>	unlimited	S
Maximum Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD <sub>HBM</sub>	2000	V
ESD Capability, Machine Model (Note 2)	ESD <sub>MM</sub>	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTIS and APPLICATION INFORMATION for Safe Operating Area.

This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per EIA/JESD22–A114

Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

#### THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, CSP4 (Note 3) Thermal Resistance, Junction-to-Air	$R_{ hetaJA}$	108	°C/W

3. Measured according to JEDEC board specification. Detailed description of the board can be found in JESD51-7

ESD Machine Model tested per EIA/JESD22-A115

Parameter	Test Conditions		Symbol	Min	Тур	Max	Unit	
Operating Input Voltage			V <sub>IN</sub>	1.9		5.5	V	
Output Voltage Accuracy	$V_{IN} = V_{OUT(NOM)} + 1 V$ 0 mA $\leq I_{OUT} \leq 450$ mA		V <sub>OUT</sub>	-2		+2	%	
Line Regulation	V <sub>OUT(NOM)</sub> + 1	$V \le V_{IN} \le 5.5 V$	Line <sub>Reg</sub>		0.02		%/V	
Load Regulation	I <sub>OUT</sub> = 1 mA	A to 450 mA	Load <sub>Reg</sub>		0.001		%/mA	
Dropout Voltage (Note 5)	I <sub>OUT</sub> = 450 mA	V <sub>OUT(NOM)</sub> = 1.8 V			300	450	C	
		V <sub>OUT(NOM)</sub> = 2.5 V			190	315	.,	
		V <sub>OUT(NOM)</sub> = 2.7 V	V <sub>DO</sub>		180	300	mV	
		V <sub>OUT(NOM)</sub> = 2.8 V			175	290		
Output Current Limit	V <sub>OUT</sub> = 90%	VOUT(NOM)	I <sub>CL</sub>	450	700			
Short Circuit Current	V <sub>OUT</sub>	= 0 V	I <sub>SC</sub>		690		mA	
Quiescent Current	I <sub>OUT</sub> =	0 mA	l <sub>Q</sub>		55	65	μΑ	
Shutdown Current	V <sub>EN</sub> ≤ 0.4 V,	V <sub>IN</sub> = 4.8 V	I <sub>DIS</sub>		0.01	1	μΑ	
EN Pin Threshold Voltage	EN Input Voltage "H"		V <sub>ENH</sub>	1.2			v	
	EN Input Voltage "L"		V <sub>ENL</sub>			0.4		
EN Pull Down Current	V <sub>EN</sub> = 4.8 V		I <sub>EN</sub>		0.2	0.5	μΑ	
Power Supply Rejection Ratio	I <sub>OUT</sub> = 20 mA	f = 100 Hz f = 1 kHz f = 10 kHz f = 100 kHz	PSRR		91 98 82 48		dB	
Output Voltage Noise	f = 10 Hz to 100 kHz	I <sub>OUT</sub> = 1 mA I <sub>OUT</sub> = 250 mA	V <sub>N</sub>		14 10		μV <sub>RMS</sub>	
Thermal Shutdown Threshold	Temperature rising		T <sub>SDH</sub>		160		°C	
	Temperature falling		T <sub>SDL</sub>		140		°C	
Active output discharge resistance	V <sub>EN</sub> < 0.4 V, Version A only		R <sub>DIS</sub>		280		Ω	
Line transient (Note 6)			Trop	-1			m)/	
	V <sub>IN</sub> = (V <sub>OUT(NOM)</sub> + 1 1 V) in 30 μs,	.6 V) to $(V_{OUT(NOM)} + I_{OUT} = 1 \text{ mA}$	Tran <sub>LINE</sub>			+1	- mV	
Load transient (Note 6)	I <sub>OUT</sub> = 1 mA to 450 mA in 10 μs		Tran <sub>LOAD</sub>	-40			mV	
	I <sub>OUT</sub> = 450 mA to 1mA in 10 μs				Ĩ	+40		

<b>ELECTRICAL CHARACTERISTICS</b> $-40^{\circ}C \le T_J \le 125^{\circ}C$ ; $V_{IN} = V_{OUT(NOM)} + 1$ V; $I_{OUT} = 1$ mA, $C_{IN} = C_{OUT} = 1$ µF, unless otherwise
noted. $V_{EN} = 1.2$ V. Typical values are at $T_J = +25^{\circ}C$ (Note 4).

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at  $T_A = 25^{\circ}C$ .

Low duty cycle pulse techniques are used during the testing to maintain the junction temperature as close to ambient as possible. 5. Dropout voltage is characterized when V<sub>OUT</sub> falls 100 mV below V<sub>OUT(NOM)</sub>.

6. Guaranteed by design.









	RMS Output Noise (μV)			
Ι <sub>ουτ</sub>	10 Hz – 100 kHz	100 Hz – 100 kHz		
1 mA	14.62	14.10		
10 mA	11.12	10.48		
250 mA	10.37	9.82		
450 mA	10.22	9.62		

Figure 21. Output Voltage Noise Spectral Density – V<sub>OUT</sub> = 1.8 V



	RMS Output Noise (μV)			
lout	10 Hz – 100 kHz	100 Hz – 100 kHz		
1 mA	16.90	15.79		
10 mA	12.64	11.13		
250 mA	11.96	10.64		
450 mA	11.50	10.40		









### APPLICATIONS INFORMATION

#### General

The NCP148 is an ultra-low noise 450 mA low dropout regulator designed to meet the requirements of RF applications and high performance analog circuits. The NCP148 device provides very high PSRR and excellent dynamic response. In connection with low quiescent current this device is well suitable for battery powered application such as cell phones, tablets and other. The NCP148 is fully protected in case of current overload, output short circuit and overheating.

#### Input Capacitor Selection (CIN)

Input capacitor connected as close as possible is necessary for ensure device stability. The X7R or X5R capacitor should be used for reliable performance over temperature range. The value of the input capacitor should be 1  $\mu$ F or greater to ensure the best dynamic performance. This capacitor will provide a low impedance path for unwanted AC signals or noise modulated onto constant input voltage. There is no requirement for the ESR of the input capacitor but it is recommended to use ceramic capacitors for their low ESR and ESL. A good input capacitor will limit the influence of input trace inductance and source resistance during sudden load current changes.

#### **Output Decoupling (COUT)**

The NCP148 requires an output capacitor connected as close as possible to the output pin of the regulator. The recommended capacitor value is 1  $\mu$ F and X7R or X5R dielectric due to its low capacitance variations over the specified temperature range. The NCP148 is designed to remain stable with minimum effective capacitance of 0.7  $\mu$ F to account for changes with temperature, DC bias and package size. Especially for small package size capacitors such as 0201 the effective capacitance drops rapidly with the applied DC bias. Please refer Figure 37.



Figure 37. Capacity vs DC Bias Voltage

There is no requirement for the minimum value of Equivalent Series Resistance (ESR) for the  $C_{OUT}$  but the maximum value of ESR should be less than 2  $\Omega$  Larger output capacitors and lower ESR could improve the load

transient response or high frequency PSRR. It is not recommended to use tantalum capacitors on the output due to their large ESR. The equivalent series resistance of tantalum capacitors is also strongly dependent on the temperature, increasing at low temperature.

#### **Enable Operation**

The NCP148 uses the EN pin to enable/disable its device and to deactivate/activate the active discharge function.

If the EN pin voltage is <0.4 V the device is guaranteed to be disabled. The pass transistor is turned–off so that there is virtually no current flow between the IN and OUT. The active discharge transistor is active so that the output voltage  $V_{OUT}$  is pulled to GND through a 280  $\Omega$  resistor. In the disable state the device consumes as low as typ. 10 nA from the  $V_{IN}$ .

If the EN pin voltage >1.2 V the device is guaranteed to be enabled. The NCP148 regulates the output voltage and the active discharge transistor is turned–off.

The EN pin has internal pull-down current source with typ. value of 200 nA which assures that the device is turned-off when the EN pin is not connected. In the case where the EN function isn't required the EN should be tied directly to IN. After device is enabled by EN pin soft start feature ensure that maximal Vout slew rate will be slower than 30 mV/ $\mu$ s. The soft start function also protects powered device before possible damage by large inrush current.

#### **Output Current Limit**

Output Current is internally limited within the IC to a typical 700 mA. The NCP148 will source this amount of current measured with a voltage drops on the 90% of the nominal  $V_{OUT}$ . If the Output Voltage is directly shorted to ground ( $V_{OUT} = 0$  V), the short circuit protection will limit the output current to 690 mA (typ). The current limit and short circuit protection will work properly over whole temperature range and also input voltage range. There is no limitation for the short circuit duration.

#### Thermal Shutdown

When the die temperature exceeds the Thermal Shutdown threshold ( $T_{SD} - 160^{\circ}$ C typical), Thermal Shutdown event is detected and the device is disabled. The IC will remain in this state until the die temperature decreases below the Thermal Shutdown Reset threshold ( $T_{SDU} - 140^{\circ}$ C typical). Once the IC temperature falls below the 140°C the LDO is enabled again. The thermal shutdown feature provides the protection from a catastrophic device failure due to accidental overheating. This protection is not intended to be used as a substitute for proper heat sinking.

#### **Power Dissipation**

As power dissipated in the NCP148 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part.

The maximum power dissipation the NCP148 can handle is given by:

$$P_{D(MAX)} = \frac{\left[125^{\circ}C - T_{A}\right]}{\theta_{JA}}$$
 (eq. 1)

The power dissipated by the NCP148 for given application conditions can be calculated from the following equations:

$$\mathsf{P}_{\mathsf{D}} \approx \mathsf{V}_{\mathsf{IN}} \cdot \mathsf{I}_{\mathsf{GND}} + \mathsf{I}_{\mathsf{OUT}} (\mathsf{V}_{\mathsf{IN}} - \mathsf{V}_{\mathsf{OUT}}) \qquad (\mathsf{eq. 2})$$



Figure 38.  $\theta_{JA}$  and P<sub>D (MAX)</sub> vs. Copper Area (CSP4)

#### **Reverse Current**

The PMOS pass transistor has an inherent body diode which will be forward biased in the case that  $V_{OUT} > V_{IN}$ . Due to this fact in cases, where the extended reverse current condition can be anticipated the device may require additional external protection.

#### **Power Supply Rejection Ratio**

The NCP148 features very high Power Supply Rejection ratio. If desired the PSRR at higher frequencies in the range 100 kHz - 10 MHz can be tuned by the selection of C<sub>OUT</sub> capacitor and proper PCB layout.

#### **PCB Layout Recommendations**

To obtain good transient performance and good regulation characteristics place  $C_{IN}$  and  $C_{OUT}$  capacitors close to the device pins and make the PCB traces wide. In order to minimize the solution size, use 0402 or 0201 capacitors with appropriate capacity. Larger copper area connected to the pins will also improve the device thermal resistance. The actual power dissipation can be calculated from the equation above (Equation 2). Expose pad can be tied to the GND pin for improvement power dissipation and lower device temperature.

Device	Nominal Output Voltage	Description	Marking	Rotation	Package	Shipping
NCP148AFCT180T2G	1.8 V		Т	270°		
NCP148AFCT250T2G	2.5 V		V	0°		
NCP148AFCT255T2G	2.55 V	450 mA, Active Discharge	4	180°	50717	5000 / Tape &
NCP148AFCT260T2G	2.6 V		V	90°	567JZ	Reel
NCP148AFCT270T2G	2.7 V		Y	0°		
NCP148AFCT280T2G	2.8 V		6	<b>0</b> °	1	

#### ORDERING INFORMATION

### PACKAGE DIMENSIONS

WLCSP4, 0.64x0.64 CASE 567JZ

**ISSUE A** 











- 2
- CONTROLLING DIMENSION: MILLIMETERS. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS. 3.

ROWING OF SOLDER BALLS.						
	MILLIMETERS					
DIM	MIN NOM MAX					
Α			0.33			
A1	0.04 0.06 0.08					
A2	0.23 REF					
b	0.195	0.210	0.225			
D	0.610	0.640	0.670			
Е	0.610	0.640	0.670			
е	0.35 BSC					

#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and ware trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="https://www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, Buyer is responsible for its products and applications using ON Semiconductor products, including compliances which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative